



Resonant scattering processes at work in an active region as detected in the transition region Si IV lines near 140 nm with IRIS

C. Gontikakis, RCAAM, Academy of Athens, Greece J.-C. Vial Institut d'Astrophysique Spatiale, France

IRIS-9, Göttingen, 25-29 June 2018

Contributed Talk

1. Fundamental physical processes and modeling

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C. Gontikakis¹, J.-C. Vial²

¹Research Center for Astronomy and Applied Mathematics, Academy of Athens, 4 Soranou Efessiou Str., Athens 11527, Greece,

² Université Paris Sud, Institut d'Astrophysique Spatiale, UMR8617, 91405, Orsay, France, CNRS, Institut d'Astrophysique Spatiale, UMR8617, 91405, Orsay, France

The emission spectrum of the solar transition region is analysed, most of the times, assuming that the photons are emitted only through the electronic collisions processes. As for resonant scattering, it is taken into account only in solar regions such as prominences or the corona. Line doublets formed in the transition region, such as the Si IV 1399Å, 1402Å, recorded with IRIS can be used, through their line ratio, to evaluate the importance of resonant scattering and of optical thickness. We present locations of active region NOAA 12529 where we detected cases with line ratios in the range of $2 < 1393/1402 \leq 3$ suggesting resonant scattering, as well as line ratios in the range of $1.3 \leq 1393/1402 \leq 1.6$ where optical thickness is important. Optical thickness is found along fibril-like structures while resonant scattering seems to be important in bright grains. For the profiles showing resonant scattering we were able to estimate physical parameters such as the electron densities (10^9 up to 10^{12} cm⁻³). Our work suggests that radiation scattering should be taken into account when analyzing transition region lines.





Resonant scattering processes at work in an active region as detected in the transition region Si IV lines near 140 nm with IRIS

C. Gontikakis, RCAAM, Academy of Athens, Greece J.-C. Vial Institut d'Astrophysique Spatiale, France Observing date : April 18, 2016 Starting time : 01:14:09 UT Ending time : 02:16:05 UT

NOAA 12529



SDO/AIA 1700Å 2016-04-18T01:00:29 UT

Intensity image Si IV 1393Å IRIS raster



FOV 140 x 186" Exp time = 8 s, dx=0.33"



Gontikakis, Winebarger, Patsourakos (2013) A&A Gontikakis, Vial (2016) A&A



 I_{13}/I_{12} = versus 1393Å peak intensity

Only 29 pixels I_{13}/I_{12} >2

However ! We re-estimated the error bars





I₁₃∕I₁₂>2 ∼6000 pixels

(~3% of FOV)

I₁₃/**I**₁₂ <1.6

>300 pixels on fibrils



$$I_{13}(\nu) = h\nu_{13}(n_i n_e C_{13} \psi_{\nu} + n_i B_{13} \bar{J}_{13}(\nu)) \frac{L}{4\pi}, \quad 1393\text{\AA}$$
$$I_{12}(\nu) = h\nu_{12}(n_i n_e C_{12} \psi_{\nu} + n_i B_{12} \bar{J}_{12}(\nu)) \frac{L}{4\pi}. \quad 1402\text{\AA}$$

 n_e decreases as a function of I_{13}/I_{12} .

Kohl & Withbroe1982 ApJ Noci etal 1987 ApJ Gontikakis etal 2013 A&A

 $I_{13}/I_{12} > 2.4$ Scatterings/Collisions> 0.5

1) $\boldsymbol{\tau}$ computed as a function of I_{13}/I_{12} .

$$\frac{I_{13}}{I_{12}} = \frac{\int (1 - e^{-\tau_{13}0}e^{-0.5y^2})dy}{\int (1 - e^{-\frac{\tau_{13}0}{2}e^{-0.5y^2}})dy},$$

Buchlin & Vial 2009 A&A Dere & Mason 1993 Sol. Phys.



τ (1.5 - 2.6)

2) Measurement of fibril size L, using Gaussian fits along the slit across the fibrils.

L structure size along LOS [Mm]

Electron density n_{e} calculated as a function of $\,\tau$ and L

 $\tau = n_e 0.8 \text{ Ab } l_0 f(T) L$



Ab, f(T) from CHIANTI v.7 filling factor =1

n_e from O IV 1399Å/1401.Å compared with **n**_e from opacity profiles (fibrils)



Pressure equilibrium: $n_e(OIV) T(OIV) = n_e(op)T(op)$

Conclusions

Doublets used to measure resonant scattering and opacity

3% individual profiles affected by resonant scattering

Resonant scattering when **N**_e low Resonant scattering important in and around many active regions ?

~300 Optically thick profiles over fibrils Measured τ : 1.5 – 2.6

Two tools to measure electron densities

 $\mathbf{n}_{\mathbf{e}}$ (O IV), $\mathbf{n}_{\mathbf{e}}$ (optically thick)

Measurements agree for 27% of cases For Temperatures 80000K and 125000K

C. Gontikakis thanks Université Paris-Sud France Many thanks to B. De Pontieu, W. Liu, J.-P. Wuelser for their comments Collision term and radiative scattering term

$$\begin{split} I_{13}(\nu) &= h \nu_{13}(n_i \, n_e C_{13} \, \psi_{\nu} \ + n_i B_{13} \bar{J}_{13}(\nu)) \frac{L}{4 \, \pi}, \\ I_{12}(\nu) &= h \nu_{12}(n_i \, n_e C_{12} \, \psi_{\nu} \ + n_i B_{12} \bar{J}_{12}(\nu)) \frac{L}{4 \, \pi}. \end{split}$$

Incident intensities J13, J12

The diffusion region is at altitude **h** above the disk and is illuminated 'from below'

Free parameters : Altitude h, Temperature T

 $\begin{array}{l} n_{i} \ n_{e} \ \ density \ of \ ion, \ electrons \\ C_{13}(T) \ \ collision \ frequency \ (CHIANTI v.7) \\ \Psi_{v} \ , \ \Phi_{v} \ \ emission, absorption \ profiles \\ B_{13}, B_{12} \ \ Einstein \ \ coefficiens \\ L \ \ line \ of \ sight \ length \end{array}$

Examples of individual profiles

Resonant scattering profiles

Optically thick profiles



I₁₃/I₁₂=1.5

